

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

CPH6538 — NPN Epitaxial Planar Silicon Transistor DC / DC Converter Applications

Features

- · Small-sized package with two NPN transistors (30C02CH equivalency) contained in one package
- V_{CEO}=30V, I_C=0.7A
- Low Collector-to-Emitter Saturation Voltage V_{CE}(sat)=85mV(typ.)@I_C=0.2A
- High-speed switching tf=40ns(typ.)@IC=0.3A
- · Halogen free Compliance

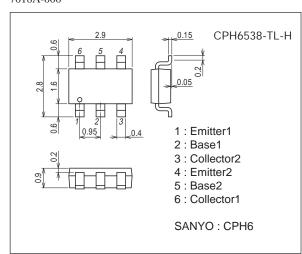
Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		40	V
Collector-to-Emitter Voltage	V _{CEO}		30	V
Emitter-to-Base Voltage	VEBO		5	V
Collector Current	IC		700	mA
Collector Current (Pulse)	ICP		1.4	Α
Collector Dissipation	PC	When mounted on ceramic substrate (600mm ² ×0.8mm) 1unit	0.6	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Package Dimensions

unit : mm (typ) 7018A-006



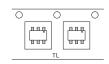
Product & Package Information

• Package : CPH6

• JEITA, JEDEC : SC-74, SOT-26, SOT-457

• Minimum Packing Quantity : 3,000 pcs./reel

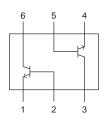
Packing Type: TL



Marking



Electrical Connection

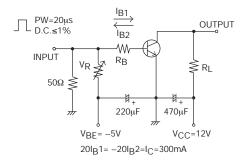


http://semicon.sanyo.com/en/network

Electrical Characteristics at Ta=25°C

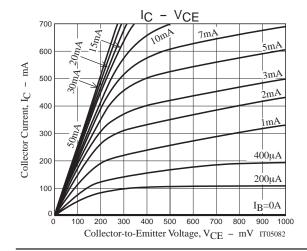
Parameter	Symbol	Conditions	Ratings			Unit
		Conditions	min	typ	max	Uill
Collector Cutoff Current	ICBO	V _{CB} =30V, I _E =0A			100	nA
Emitter Cutoff Current	IEBO	VEB=4V, IC=0A			100	nA
DC Current Gain	hFE	V _{CE} =2V, I _C =50mA	300		800	
Gain-Bandwidth Product	fŢ	V _{CE} =2V, I _C =50mA		540		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		3.3		pF
Collector-to-Emitter Saturation Voltage	VCE(sat)	IC=200mA, IB=10mA		85	190	mV
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C =200mA, I _B =10mA		0.9	1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=10μA, IE=0A	40			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =1mA, R _{BE} =∞	30			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =10μA, I _C =0A	5			V
Turn-On Time	ton			35		ns
Storage Time	t _{stg}	See specified Test Circuit.		255	·	ns
Fall Time	tf			40		ns

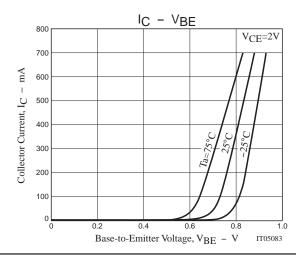
Switching Time Test Circuit

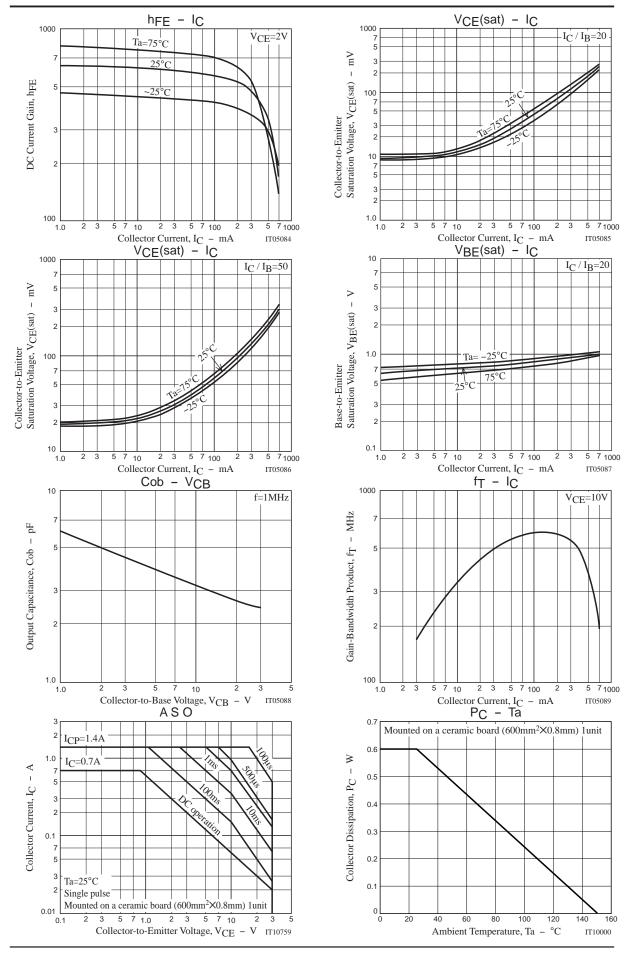


Ordering Information

Device	Device Package		memo	
CPH6538-TL-H CPH6		3,000pcs./reel	Pb Free and Halogen Free	





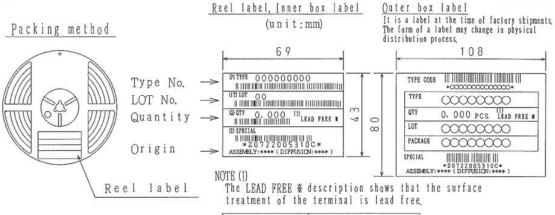


Embossed Taping Specification

CPH6538-TL-H

1. Packing Format

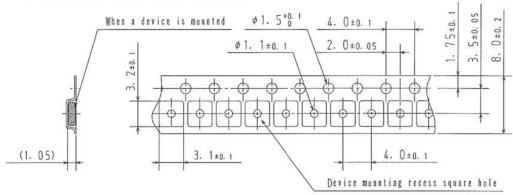
Package Name Carrier Tape Type CPH6 CPH6	Carrier Tape	Maximum Number of devices contained (pcs)			Packing format		
	Type	Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)	
	CPH6	3, 000	15, 000	90, 000		6 inner boxes contained Dimensions:mm (external) $440 \times 195 \times 210$	

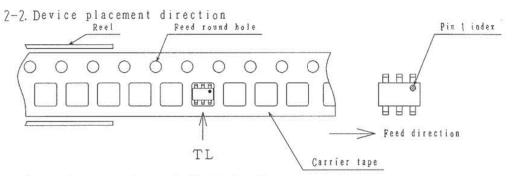


Label JEITA Phase LEAD FREE 3 JEITA Phase 3A LEAD FREE 4 JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)





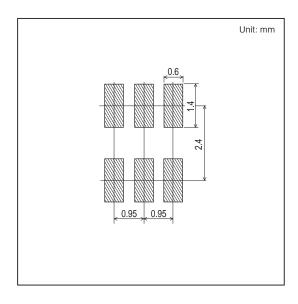
Those with pin 1 index on the feed hole side ·····TL

Outline Drawing

CPH6538-TL-H

Mass (g) Unit 0.015 mm 0. 15^{+0. 1}_{-0. 05} 2. 9±0. 1 0, 6±0, 1 [*1][*1] 0. 05±0. 05 2. 8±0. 15 1. 6±0. 1 [*1] 0. 95 O. 6±0. 1 PIN#1 0.05 \$ *1:Lot indication

Land Pattern Example



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